onsemi

Digital FET, P-Channel FDV304P, FDV304P-F169

General Description

This P-Channel enhancement mode field effect transistors is produced using **onsemi**'s proprietary, high cell density, DMOS technology. This very high density process is tailored to minimize on-state resistance at low gate drive conditions. This device is designed especially for application in battery power applications such as notebook computers and cellular phones. This device has excellent on-state resistance even at gate drive voltages as low as 2.5 V.

Features

- -25 V, -0.46 A Continuous, -1.5 A Peak
 - $R_{DS(on)} = 1.1 \Omega @ V_{GS} = -4.5 V$
 - $R_{DS(on)} = 1.5 \ \Omega @ V_{GS} = -2.7 \ V$
- Very Low Level Gate Drive Requirements Allowing Direct Operation in 3 V Circuits. V_{GS(th)} < 1.5 V
- Gate–Source Zener for ESD Ruggedness. > 6 kV Human Body Model

ABSOLUTE MAXIMUM BATINGS ($T_A = 25^{\circ}C$ unless otherwise noted.)

- Compact Industry Standard SOT-23 Surface Mount Package
- This Device is Pb-Free and Halide Free

Symbol	Parameter	Value	Unit
V _{DSS}	Drain-Source Voltage	-25	V
V _{GSS}	Gate-Source Voltage	-8	V
I _D	Drain Current – Continuous	-0.46	А
	Drain Current – Pulsed	-1.5	
PD	Maximum Power Dissipation	0.35	W
T _J , T _{STG}	Operating and Storage Temperature Range	–55 to 150	°C
ESD	Electrostatic Discharge Rating MIL-STD-883D Human Body Model (100 pF/1500 Ω)	6.0	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

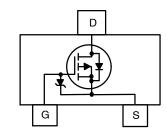
THERMAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Value	Unit
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient	357	°C/W

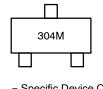


SOT-23-3 CASE 318-08

ELECTRICAL CONNECTION



MARKING DIAGRAM



304 = Specific Device Code M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
FDV304P	SOT-23-3 (Pb-Free, Halide-Free)	3000 / Tape & Reel
FDV304P-F169	SOT-23-3 (Pb-Free, Halide-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, <u>BRD8011/D</u>.

FDV304P, FDV304P-F169

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit		
OFF CHARACT	OFF CHARACTERISTICS							
BV _{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_D = –250 μA	-25	-	-	V		
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	I_D = –250 $\mu A,$ Referenced to 25°C	-	-22	-	mV/°C		
I _{DSS}	Zero Gate Voltage Drain Current	V_{DS} = -20 V, V_{GS} = 0 V	-	-	-1	μΑ		
		V_{DS} = –20 V, V_{GS} = 0 V, T_J = 55°C	-	-	-10			
I _{GSS}	Gate-Body Leakage Current	$V_{GS} = -8 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	-100	nA		

ON CHARACTERISTICS (Note 1)

$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp. Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C	-	2.1	-	mV/°C
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-0.65	-0.86	-1.5	V
R _{DS(on)}	Static Drain-Source On-Resistance	V_{GS} = -2.7 V, I _D = -0.25 A	-	1.22	1.5	Ω
		V_{GS} = -4.5 V, I_D = -0.5 A	-	0.87	1.1	
		V_{GS} = –4.5 V, I_D = –0.5 A, T_J = 125°C	-	1.21	2	
I _{D(on)}	On-State Drain Current	V_{GS} = -2.7 V, V_{DS} = -5 V	-0.5	_	-	А
		V_{GS} = -4.5 V, V_{DS} = -5 V	-1	_	-	
9 _{FS}	Forward Transconductance	$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -0.5 \text{ A}$	-	0.8	-	S

DYNAMIC CHARACTERISTICS

C _{iss}	Input Capacitance	V_{DS} = -10 V, V_{GS} = 0 V, f = 1.0 MHz	—	63	-	pF
C _{oss}	Output Capacitance		-	34	-	
C _{rss}	Reverse Transfer Capacitance		-	10	-	

SWITCHING CHARACTERISTICS (Note 1)

t _{D(on)}	Turn-On Delay Time	$V_{DD} = -6 \text{ V, } I_D = -0.5 \text{ A,} \\ V_{GS} = -4.5 \text{ V, } \text{R}_{GEN} = 50 \ \Omega$	-	7	20	ns
t _r	Turn-On Rise Time		-	8	20	
t _{D(off)}	Turn-Off Delay Time		-	55	110	
t _f	Turn-Off Fall Time		-	35	70	
Qg	Total Gate Charge	$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -0.25 \text{ A},$ $V_{GS} = -4.5 \text{ V}$	-	1.1	1.5	nC
Q _{gs}	Gate-Source Charge		-	0.32	-	
Q _{gd}	Gate-Drain Charge		-	0.25	_	

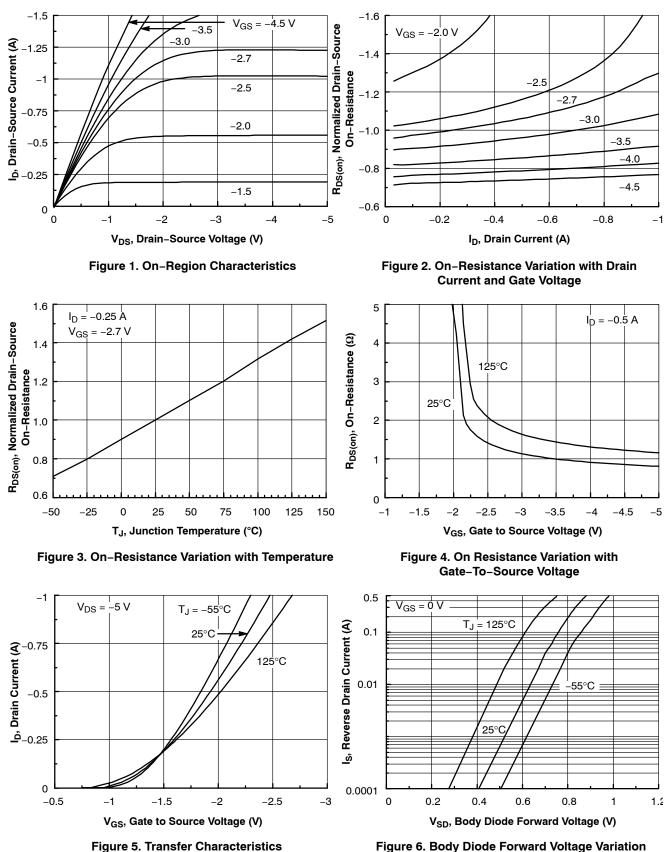
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS

۱ _S	Maximum Continuous Drain-Source Diode Forward Current		-	-0.5	А
V _{SD}	Drain–Source Diode Forward Voltage $V_{GS} = 0 \text{ V}, I_S = -0.5 \text{ A}$ (Note 1)	-	-0.89	-1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

FDV304P, FDV304P-F169

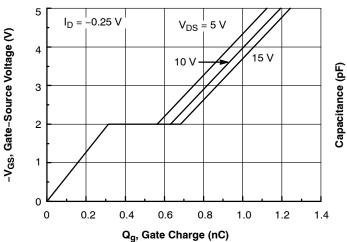
TYPICAL CHARACTERISTICS





FDV304P, FDV304P-F169

TYPICAL CHARACTERISTICS (continued)





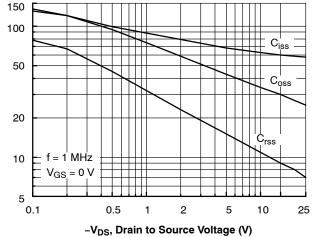


Figure 8. Capacitance Characteristics

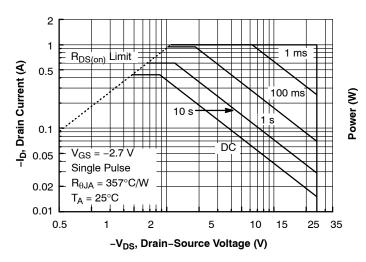


Figure 9. Maximum Safe Operating Area

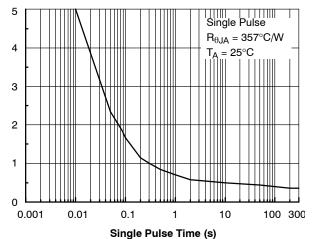


Figure 10. Maximum Pulse Maximum Power Dissipation

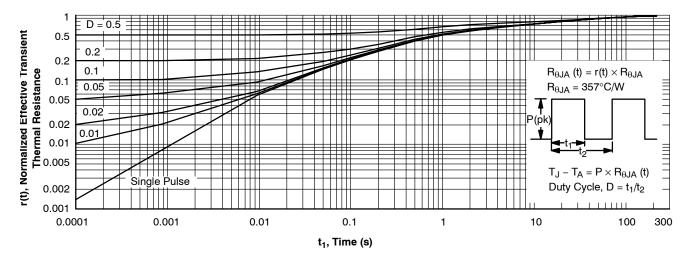


Figure 11. Transient Thermal Response Curve





© Semiconductor Components Industries, LLC, 2019

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi: FDV304P